



ELECTRONICS, INC.
44 FARRAND STREET
BLOOMFIELD, NJ 07003
(973) 748-5089

NTE6113, NTE6115, & NTE6121 Industrial Rectifier, 1200 Amp

Absolute Maximum Ratings: ($T_J = +175^{\circ}\text{C}$ unless otherwise specified)

Repetitive Voltage, V_{RRM}

NTE6113	600V
NTE6115	1200V
NTE6121	1600V

Non-Repetitive Voltage, V_{RSM}

NTE6113	700V
NTE6115	1300V
NTE6121	1700V

Average Forward Current (Half Sine Wave), $I_{F(AV)}$

+55°C Heatsink Temperature (Double Side Cooled)	1625A
+100°C Heatsink Temperature (Single Side Cooled)	800A

RMS Current (+25°C Heatsink Temperature, Double Side Cooled), $I_{F(RMS)}$ 2950A

DC Forward Current (+25°C Heatsink Temperature, Double Side Cooled), I_F 2760A

Peak One-Cycle Surge (Non-Repetitive) of Forward Current (10ms Duration), I_{FSM}

60% V_{RRM} Re-Applied	15400A
$V_R \leq 10V$	17700A

Maximum Permissible Surge Energy, I^2t

10ms Duration, 60% V_{RRM} Re-Applied	1180000A ² s
10ms Duration, $V_R \leq 10V$	1560000A ² s
3ms Duration, $V_R \leq 10V$	1160000A ² s

Operating Temperature Range, T_{HS} -30° to +175°C

Storage Temperature Range, T_{stg} -40° to +200°C

Typical Thermal Resistance, Junction-to-Heatsink, $R_{th(j-hs)}$

(For a Device with a Max Forward Volt-Drop)

Single Side Cooled	0.065°C/W
Double Side Cooled	0.033°C/W

Electrical Characteristics: (Maximum Values @ $T_J = +175^{\circ}\text{C}$ unless otherwise specified)

Peak Forward Voltage Drop ($I_{FM} = 3770A$), V_{FM} 1.93V

Forward Conduction Threshold Voltage, V_O 0.87V

Forward Conduction Slope Resistance, r 0.28mΩ

Peak Reverse Current (At V_{RRM}), I_{RRM} 30mA



